Therm aldiode: Recti cation of heat ux

Baowen Li^a, Lei W ang^b, and G iulio Casati^{c;d;a}

^a Departm ent of Physics, National University of Singapore, Singapore 117542, Republic of Singapore

^bTen asek Laboratories, National University of Singapore, Singapore 119260, Republic of Singapore

^cInternational Center for Nonlinear and Complex Systems, Universita' degli studi dell'Insubria, Como

^d Istituto Nazionale di Fisica della Materia, Unita' di Como, Italy, and

Istituto Nazionale di Fisica Nucleare, sezione di Milano, Milano, Italy

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By coupling two nonlinear one dimensional lattices, we demonstrate a therm all diode model that works in a wide range of system parameters. We provide numerical and analytical evidence for the underlying mechanism which allows heat ux in one direction while the system acts like an insulator when the temperature gradient is reversed. The possible experimental realization in nano scale systems is brie y discussed.

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The understanding of the underlying dynam icalm echanisms which determines the macroscopic laws of heat conduction is a long standing task of non-equilibrium statistical mechanics [1]. Recent years have witnessed som e in portant progress in this direction even though a satisfactory understanding is, so far, unavailable. For exam ple, it has been summ ized that for a one dimensional lattice, m om entum conservation leads, in general, to anom alous heat conduction [2], with heat conductivity which diverges with the system size L as $L^{2=5}$ [3]. If the trans-L¹⁼³ [4]. A connecverse motion is considered, then tion between the anom alous conductivity and anom alous di usion has been also established [5]. Moreover, after two decades of debates, it is now clear that exponential local instability is not a necessary condition for the validity of Fourier law [6].

A better understanding of the mechanism of heat conduction m ay also lead to potentially interesting applications based on the possibility to control the heat ow . Indeed, recently, a model for a therm al recti er has been proposed [7] in which the rectifying e ect is obtained by acting on the parameters which control the nonlinearity of the lattice. A lthough this model is far away from a realistic in plementation, nevertheless it opens the possibility to propose therm al devices which m ay have practical relevance.

In this Letter we dem onstrate, via computer simulations, the possibility to build a therm all diode by coupling two nonlinear lattices. Indeed our model allows the heat ow from one end to the other, but it inhibits the ow in the opposite direction. The model works in a wide range of system parameters and the underlying microscopic mechanism is di erent from the one in ref[7] even though it is based on the same general idea. In the present case the ratio of the heat currents in the two opposite directions is 100 times larger than that in model[7] and it is therefore su ciently large to encourage experimental work.

Our system consists of two segments of nonlinear lat-

tices coupled together by a harm onic spring with constant strength $k_{\rm int}.$ Each segment is described by the H am iltonian:

$$H = \frac{X}{2m} + \frac{p_i^2}{2} + \frac{1}{2}k(x_i - x_{i+1} - a)^2 - \frac{V}{(2)^2} \cos 2 x_i:$$
(1)

In fact, Eq. (1) is the Ham iltonian of the Frenkel-Kontorova (FK) model which is known to have norm al heat conduction [8].

For sim plicity we set the m ass of the particles and the lattice constant m = a = 1. Thus the adjustable param – eters are $(k_L; k_{int}; k_R; V_L; V_R; T_L; T_R)$, where the letter L/R indicates the left/right segment and $T_{L;R}$ is the tem – perature of the left/right heat bath. In order to reduce the num ber of adjustable param eters, we set $V_R = V_L$, $k_R = k_L$, $T_L = T_0 (1 +); T_R = T_0 (1)$ and, unless otherw ise stated, we x $V_L = 5$, $k_L = 1$ so that the adjustable param eters are reduced to four, (;; $k_{int}; T_0)$. Notice that when > 0, the left bath is at higher tem – perature and vice versa when < 0.

In our num erical simulations we use xed boundary conditions and the N particle chain is coupled, at the two ends, with heat baths at temperatures T_{L} and T_{R} respectively. We use Langevin heat baths and we have checked that our results do not depend on the particular heat bath realization (e.g. Nose-Hoover heat baths). W e then integrate the di erential equations of m otion by using the 5th-order R unge-K utta algorithm as described in [9]. We compute the temperature pro le inside the system, i.e. the local tem perature at site n de ned as $T_n = m h x_n^2 i$, where h i stands for tem poral average, and the local heat $ux J_n = khx_n (x_n)$ x_{n 1})i[1]. The simulations are performed long enough to allow the system to reach a non-equilibrium steady state where the local heat ux is constant along the chain.

In Fig. 1 we plot the heat current J versus for di erent temperatures T_0 . It is clearly seen that when > 0 the heat current increases with , while in the

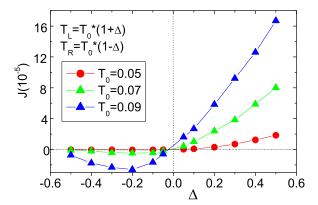


FIG.1: Heat current J versus the dimensionless temperature di erence for di erent values of T. Here the total number of particles N = 100, $k_{\rm int} = 0.05$, = 0.2. The lines are drawn to guide the eye.

region < 0 the heat current is almost zero, i.e. the system behaves as a therm al insulator. The results in Fig. 1 show that our model has the rectifying e ect in a wide range of temperatures. The rectifying e ciency depends on temperature as well as on other parameters as described below :

 $k_{\rm int}$ e ect. The interface elastic constant $k_{\rm int}$ is a very in portant parameter as it plays the role of coupling left and right lattices. By adjusting this parameter one can control the heat ow . Indeed, once the parameters of the two lattices are xed, then the smaller the coupling the smaller is the heat current through the system .

In order to describe quantitatively the recti ere - ciency we introduce the ratio, jJ_+ =J $\;jwhere\;J_+$ is the heat current (from left to right) when the bath at higher tem perature T_+ is at the left end of the chain and J $\;$ is the heat current (from right to left) when the left end of the chain is in contact with the bath at low ertem perature T $\;$.

Fig2(a) shows that, by varying $k_{\rm int}$, the recti ere – ciency $jJ_{+}=J_{-}$ jchanges from about two times at $k_{\rm int}=$ 0.5 to m one than 100 times for $k_{\rm int}$ 0.01. M one in – portantly, this gure shows that the rectifying e ect is very signi cant in a wide range of $k_{\rm int}$. In the inset of this gure we show jJ_{-} jversus $k_{\rm int}$ for a system of eight particles. It is seen that, for small $k_{\rm int}$, numerical data follow the dependence $J_{-}/k_{\rm int}^2$ over alm ost two orders of m agnitude. Therefore the ratio jJ_{+} j/ jJ_{-} j is a constant independent of $k_{\rm int}$.

Fig. 2(b) shows the temperature prole for di erent k_{int} . There exists a large temperature jump at the interface and this jump is much larger when the high temperature bath is at the right end. In this case there is very sm all temperature gradient inside each lattice and, as a consequence, the heat current is alm ost vanishing.

E ect of the lattice parameter . As it is known [8], in the FK model the elastic constant and the strength of

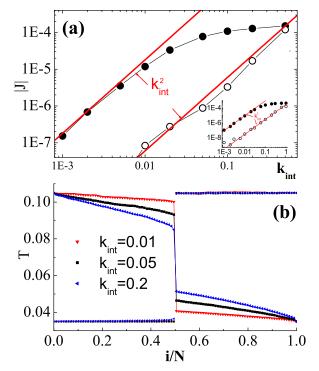


FIG.2: (a) Heat current jJ jversus the interface elastic constant $k_{\rm int}$ for N = 100, = 0.2, T₊ = 0.105, T = 0.035. The solid circles are the current J₊ while open circles are the current J . Inset in (a) is jJ jversus $k_{\rm int}$ for a system of eight particles. The solid lines in the gure and in the inset have slope equal two. (b) The temperature pro le for $k_{\rm int} = 0.01; 0.05, 0.2$ for the same parameters of (a)

the on-site potential can be scaled to a single param eter. Therefore it is su cient to study the properties of the system (1) as a function of the single param eter .

In Fig. 3, we show the current J versus for two di erent interface constants $k_{int} = 0.05$, and $k_{int} = 0.2$. This gure clearly show that in a wide range of parameters our model has a quite good rectifying e ciency, i.e. $jJ_{+} = J_{-}j_{-}$ 100.

Rectifying mechanism. To understand the underlying rectifying mechanism, let's start from the energy spectrum of the interface particles. Fig. 4 shows the phonon spectra of the left and right interface particles at different temperature when the two lattices are decoupled $(k_{int} = 0)$.

The m atch/m ism atch of the energy spectra of the two interface particles controls the heat current. It is clearly seen from F ig.4 that, if the left end is in contact with the high tem perature bath $T_{\rm L}$, and the right end with the low tem perature bath $T_{\rm R}~(< T_{\rm L})$, then the phonon spectra of the two particles at interface overlap in a large range of frequencies, thus the heat current can easily go through the system from the left end to the right end. How ever, if the left end is at low er tem perature $T_{\rm L}$ and the right end the phonon

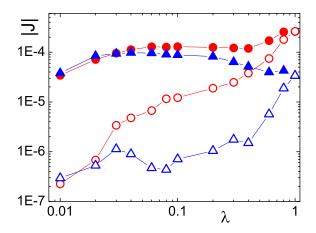


FIG.3: Heat current versus for $k_{\rm int}$ = 0.2 (circles), and $k_{\rm int}$ = 0.05 (triangles). The solid symbols refer to $T_{\rm L}$ = T_+ ; $T_{\rm R}$ = T, while empty symbols refer to $T_{\rm L}$ = T; $T_{\rm R}$ = T_+ . Here T_+ = 0:105, T = 0:035 and N = 100.

spectrum of the right interface particle is mainly in the low frequency part, while the left interface particle is in the high frequency part. Then there is almost no overlap in phonon frequency, and the heat current can hardly go through from right to left, and the system behaves as an insulator. W hy the left and right particles at the interface have so di erent phonon spectra? This can be understood from the following analysis in di erent tem perature regin es.

(1) Low temperature limit. At low temperature, the particle is conned in the valley of the on-site potential. By linearizing the equation of motion one can easily obtain the frequency band [7]:

$$p \frac{1}{V} < ! < p \frac{1}{V + 4k}$$
 (2)

For the case of Fig.4 with T = 0.01 (left) and T = 0.002 (right), this corresponds to 0.36 < !=2 < 0.48 for the left particle and to 0.16 < !=2 < 0.21 for the right particle.

As the tem perature is increased, the interparticle potential kx²=2 becomes more and more important until a critical value $T_{\rm cr}$ V=(2 \hat{j} is reached (we take the Boltzm an constant equalurity), when the kinetic energy is large enough to overcome the on-site potential barrier. At this point low frequency appears and this happens at the critical tem peratures $T_{\rm cr}$ = 0.13 for V = 5 (left), and $T_{\rm cr}$ = 0.025 for V = 1 (right). This is in quite good agreem ent with the data of Fig. 4.

(2) High temperature limit. In the high temperature limit the on-site potential can be neglected, the system is close to two coupled harm onic chains, and the phonon band is [10],

$$0 < ! < 2^{p} \overline{k};$$
 (3)

which gives 0 < !=2 < 0.32 for the left particle and

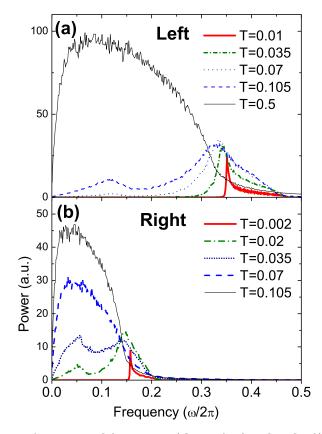


FIG. 4: Spectra of the two particles at the interface for different tem peratures at $k_{int} = 0$. (a) particle at the left side of the interface, (b) particle at the right side of the interface. Here = 0.2, N = 100.

0 < !=2 < 0.14 for the right particle, again in good agreem ent with Fig. 4.

In fact, in order to optim ize the rectifying e ect, one should avoid the overlapping of the phonon bands in the low tem perature lim it (Eq2) and that in the high tem – perature lim it (Eq3) for each segment of the system . A c-cording to the above estim ates, one should have V > 4k, which is satis ed for the case of Fig. 4.

The analysis presented here allow s also to understand why in Fig.1 there is a region of negative conductivity for $T_0 = 0.09$ and 0.5 < 0.2. Indeed in this interval it is seen that by increasing the temperature di erence between the two heat baths, the current decreases! As explained above, the reason for such unusual behavior is due to the fact that by decreasing the temperature of the left bath, the phonon spectra of the two interface particles separate one from the other.

It is worth pointing out that it is the tem perature dependence of the phonon band that makes the rectifying e ect possible. This dependence is due to the nonlinearity of the potential and therefore it should be possible to observe the rectifying e ect in any nonlinear lattice. The di erence between di erent choices of the on-site poten-

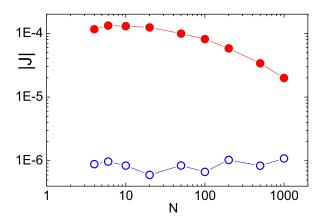


FIG.5: The nite size e ect of the rectifying e ciency. Here we plot jJ_+ j (solid circles) and jJ_- j (open circles) versus N. Parameters are = 0.2; $k_{\rm int} = 0.05$, $T_+ = 0.105$, and T = 0.035.

tial is quantitative rather than qualitative. For example, we have observed the rectifying e ect in the 4 model wherein the on-site potential is $kx^2=2 + x^4=4$, but the rectifying e ciency is not as signi cant as it is in the FK model. The main reason for the very large rectifying e - ciency in the FK model is the nite height of the on-site potential.

Finite size e ect. The results shown above are for a system with totalnum ber of particles N = 100. Since the rectifying mechanism in ourm odel is due to the coupling between two dissim ilar lattices it is reasonable to expect that the number of nonlinear oscillators will de nitely a ect the rectifying e ciency. This is shown in Figure 5 where we plot jJ_+ jand jJ_- jversus the system size N with $T_+ = 0.105$, and $T_- = 0.035$.

The decrease of the rectifying e ciency by increasing N (Fig5) and k_{int} (Fig2) can be understood in the following way. If we denote by R the sum of therm al resistances of the two segments, then the total resistance of the system is R = $R + R_{int}$, where R_{int} is interface resistance when > 0 and < 0, respectively. As $J ~=~ (T_{\rm L} ~ T_{\rm R}$)=R ~ , the rectifying e $~{\rm ciency}~{\rm is}$ $(R + R_{int}) = (R + R_{int}^{+}) \cdot N$ otice that R increases jJ₊=J j with N while R int are N independent, they decrease with increasing k_{int} , and R_{int}^{\dagger} is much smaller than R_{int} . It is therefore clear that the e ciency decreases with increasing k_{int} (Fig2) at xed N and by increasing N at xed k_{int} (Fig5).

For the data of Fig.5 we have R_{int} R, and therefore J is a small constant that is alm ost independent of N, while J₊ 1=N . As N is increased over a critical value N_c where $jJ_+ j = jJ$; the rectifying e ect vanishes. For the case of Fig. 5 this happens at N_c 10⁵. However, we should point out that the value of N_c depends on k_{int} and by decreasing k_{int} we may increase N_c.

Finally, we would like to discuss the possibility of an

experimental realization of our diode model. In our calculations, we take dimensionless units. For a typicalatom , the dimensionless temperature T_0 used in this paper is related to the real temperature T^r by T^r 10° is of the order of 10² $10^{3}T_{0}$ [8]. Therefore T_{0} room tem perature. If we consider the lattice distance of 1 A, then a lattice of 100 particles is about 10 nanom eters long, which is of a size scale that can be fabricated in now aday's laboratory. A nother problem for real experiments is that the on-site potential is due to the interaction with a substrate. In our num erical simulations, we neglect the heat current in the substrate. This may a ect the rectifying e ciency of the diode. Therefore, one needs to choose a substrate with substantially low therm alconductivity.

In sum m ary, we have devised a therm all diode by using two coupled nonlinear lattices. Our model exhibits a very signi cant rectifying e ect in a very wide range of system parameters. The underlying mechanism has been discussed as well as a possible realization of the model in a nano scale system.

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